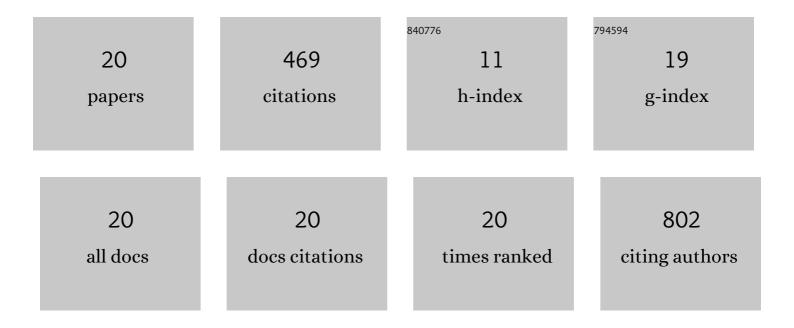
Mengjian Zhu

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/6158433/publications.pdf Version: 2024-02-01



Μενιζιμαν Ζητι

#	Article	IF	CITATIONS
1	Controllable 2H-to-1T′ phase transition in few-layer MoTe ₂ . Nanoscale, 2018, 10, 19964-19971.	5.6	99
2	Carrier Modulation of Ambipolar Few‣ayer MoTe ₂ Transistors by MgO Surface Charge Transfer Doping. Advanced Functional Materials, 2018, 28, 1704539.	14.9	88
3	Graphene Thermal Emitter with Enhanced Joule Heating and Localized Light Emission in Air. ACS Photonics, 2019, 6, 2117-2125.	6.6	53
4	High responsivity graphene photodetectors from visible to near-infrared by photogating effect. AIP Advances, 2018, 8, 115106.	1.3	46
5	Light-induced irreversible structural phase transition in trilayer graphene. Light: Science and Applications, 2020, 9, 174.	16.6	40
6	High-Performance Photodetectors Based on MoTe ₂ –MoS ₂ van der Waals Heterostructures. ACS Omega, 2022, 7, 10049-10055.	3.5	24
7	Controllable Epitaxial Growth of MoSe ₂ Bilayers with Different Stacking Orders by Reverse-Flow Chemical Vapor Deposition. ACS Applied Materials & Interfaces, 2020, 12, 23347-23355.	8.0	21
8	Highly Tunable Carrier Tunneling in Vertical Graphene–WS ₂ –Graphene van der Waals Heterostructures. ACS Nano, 2022, 16, 7880-7889.	14.6	17
9	Engineering few-layer MoTe2 devices by Co/hBN tunnel contacts. Applied Physics Letters, 2018, 112, .	3.3	14
10	High Mobility Two-Dimensional Bismuth Oxyselenide Single Crystals with Large Grain Size Grown by Reverse-Flow Chemical Vapor Deposition. ACS Applied Materials & Interfaces, 2021, 13, 49153-49162.	8.0	14
11	Phase-Changing in Graphite Assisted by Interface Charge Injection. Nano Letters, 2021, 21, 5648-5654.	9.1	12
12	Supercurrent and multiple Andreev reflections in micrometer-long ballistic graphene Josephson junctions. Nanoscale, 2018, 10, 3020-3025.	5.6	10
13	Direct Visualization and Manipulation of Stacking Orders in Few-Layer Graphene by Dynamic Atomic Force Microscopy. Journal of Physical Chemistry Letters, 2021, 12, 7328-7334.	4.6	9
14	Short channel monolayer MoS ₂ field-effect transistors defined by SiO <i> _x </i> nanofins down to 20 nm. Nanotechnology, 2019, 30, 295301.	2.6	5
15	Strain-Induced Alternating Photoluminescence Segmentation in Hexagonal Monolayer Tungsten Disulfide Grown by Physical Vapor Deposition. ACS Applied Materials & Interfaces, 2021, 13, 46164-46170.	8.0	5
16	Functional Groupâ€induced pâ€Doping of MoS ₂ by Titanium(IV) Bis(ammonium lactato) Dihydroxide Physisorption. Chemistry - an Asian Journal, 2021, 16, 1756-1761.	3.3	4
17	Electrically Controlled Wavelength-Tunable Photoluminescence from van der Waals Heterostructures. ACS Applied Materials & Interfaces, 2022, 14, 19869-19877.	8.0	4
18	Lateral and Vertical p–n Homojunctions Formed in Few-Layer MoTe ₂ with In Surface Charge-Transfer Doping. ACS Applied Electronic Materials, 2021, 3, 3428-3435.	4.3	3

#	Article	IF	CITATIONS
19	Ultrafast Photoluminescence from Suspended Gold/Graphene Hybrid Structures. Journal of Physical Chemistry C, 2019, 123, 21265-21270.	3.1	1
20	Fabrication and electron transport characteristics of suspended Graphene/hBN heterostructure Devices. Journal of Physics: Conference Series, 2022, 2230, 012028.	0.4	0